

Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of http://www.nxp.com, http://www.nxp.com, http://www.nexperia.com/, http://www.nexperia.com/, use http://www.nexperia.com/

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use salesaddresses@nexperia.com (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

- © Nexperia B.V. (year). All rights reserved.

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

74HC4066; 74HCT4066

Quad single-pole single-throw analog switch Rev. 8 — 3 December 2015

Product data sheet

1. **General description**

The 74HC4066; 74HCT4066 is a quad single pole, single throw analog switch. Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When nE is LOW, the analog switch is turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features and benefits 2.

- Input levels nE inputs:
 - ◆ For 74HC4066: CMOS level
 - ◆ For 74HCT4066: TTL level
- Low ON resistance:
 - 50 Ω (typical) at $V_{CC} = 4.5 \text{ V}$
 - ◆ 45 Ω (typical) at V_{CC} = 6.0 V
 - 35 Ω (typical) at $V_{CC} = 9.0 \text{ V}$
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

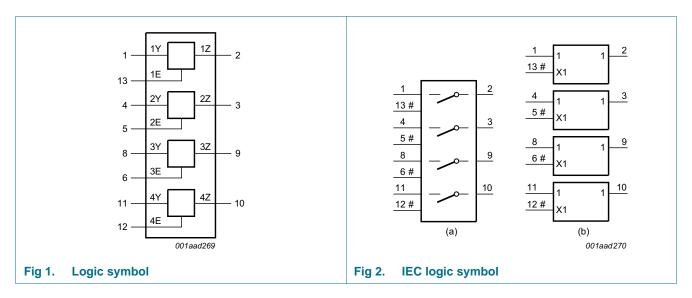


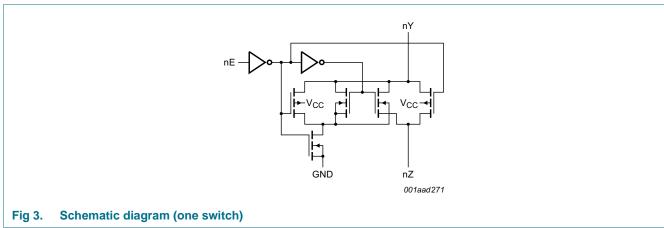
3. Ordering information

Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74HC4066D	−40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1	
74HCT4066D			3.9 mm		
74HC4066DB	−40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body	SOT337-1	
74HCT4066DB			width 5.3 mm		
74HC4066PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body	SOT402-1	
74HCT4066PW			width 4.4 mm		
74HC4066BQ	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very	SOT762-1	
74HCT4066BQ			thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm		

4. Functional diagram



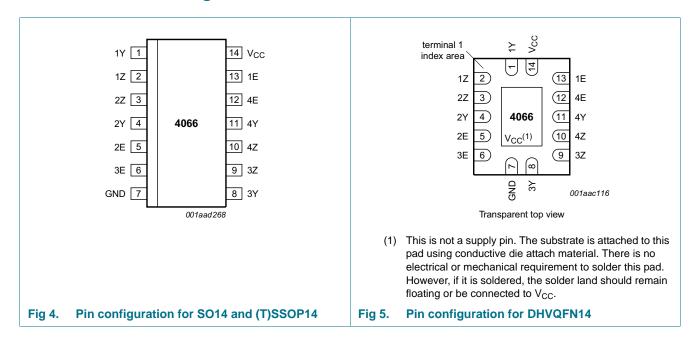


74HC_HCT4066

All information provided in this document is subject to legal disclaimers.

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

•		
Symbol	Pin	Description
1Z, 2Z, 3Z, 4Z	2, 3, 9, 10	independent input or output
1Y, 2Y, 3Y, 4Y	1, 4, 8, 11	independent input or output
GND	7	ground (0 V)
1E, 2E, 3E, 4E	13, 5, 6, 12	enable input (active HIGH)
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table[1]

Input nE	Switch
L	OFF
Н	ON

[1] H = HIGH voltage level;

L = LOW voltage level.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{SK}	switch clamping current	$V_{SW} < -0.5 \text{ V or } V_{SW} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{SW}	switch current	$V_{SW} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±25	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-	-50	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]			
		SO14, (T)SSOP14 and DHVQFN14 packages		-	500	mW
Р	power dissipation	per switch		-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn. In this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or GND.

For (T)SSOP14 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

For DHVQFN14 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	7	4HC406	6	74HCT4066			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V_{SW}	switch voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
	and fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	35	-	-	-	ns/V

^[2] For SO14 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

9. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4066 and 74HCT4066

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see <u>Figure 6</u>.

 V_{is} is the input voltage at a Yn or \overline{Z} terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4066: V_{CC} – GND = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4066: V_{CC} – GND = 4.5 V.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	V _{is} = V _{CC} to GND						
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 100 \mu\text{A}$	-	-	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	54	-	118	142	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	42	-	105	126	Ω
		$V_{CC} = 9.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	32	-	88		Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = GND						
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 100 \mu\text{A}$	-	80	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	35	-	95	115	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	27	-	82	100	Ω
		$V_{CC} = 9.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	20	-	70	85	Ω
		$V_{is} = V_{CC}$						
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 100 \mu\text{A}$	-	100	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	42	-	106	128	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	35	-	94	113	Ω
		$V_{CC} = 9.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	20	-	78	95	Ω
ΔR_{ON}	ON resistance	V _{is} = V _{CC} to GND						
	mismatch between channels	$V_{CC} = 2.0 \text{ V}$ [2]	-	-	-	-	-	Ω
	OHALITICIS	V _{CC} = 4.5 V	-	5	-	-	-	Ω
		V _{CC} = 6.0 V	-	4	-	-	-	Ω
		V _{CC} = 9.0 V	-	3	-	-	-	Ω

^[1] Typical values are measured at T_{amb} = 25 °C.

^[2] At supply voltages (V_{CC} – GND) approaching 2 V, the analog switch ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

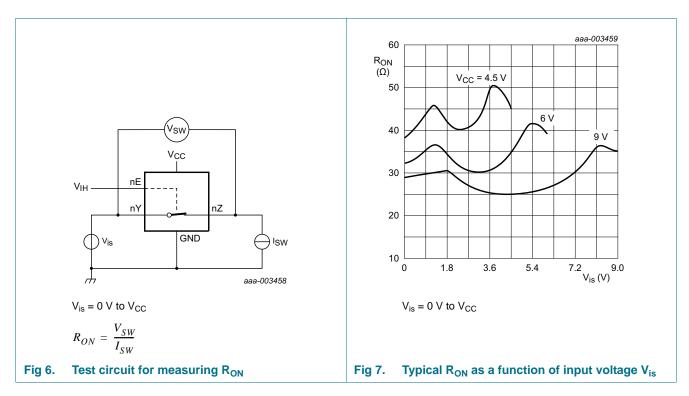


Table 7. Static characteristics 74HC4066

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		$V_{CC} = 4.5 \text{ V}$	3.15	2.4	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
_		$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.80	V
		V _{CC} = 9.0 V	-	4.3	2.70	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
ı İI		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	±1.0	μΑ

 Table 7.
 Static characteristics 74HC4066 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	20.0	μΑ
		V _{CC} = 10.0 V	-	-	40.0	μΑ
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance		-	8	-	pF
T _{amb} = -4	0 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		$V_{CC} = 4.5 \text{ V}$	3.15	-	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	-	-	V
		$V_{CC} = 9.0 \text{ V}$	6.3	-	-	V
V _{IL}	LOW-level input voltage $V_{CC} = 2.0 \text{ V}$	-	0.50	V		
/ _{IL}		$V_{CC} = 4.5 \text{ V}$	-	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.80	V
		$V_{CC} = 9.0 \text{ V}$	-	-	2.70	V
I _I	input leakage current	$V_I = V_{CC}$ or GND	40.0 - 3.5 8			
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	40	μΑ
		V _{CC} = 10.0 V	-	-	80	μΑ

^[1] Typical values are measured at T_{amb} = 25 °C.

Table 8. Static characteristics 74HCT4066

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

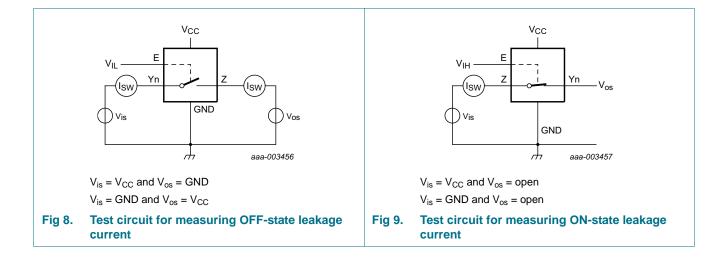
Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit			
$T_{amb} = -40$	$T_{amb} = -40$ °C to +85 °C								
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	V			
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V			
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ			

Table 8. Static characteristics 74HCT4066 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	±1.0	μА
lcc	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	20.0	μА
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	100	450	μА
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance		-	8	-	pF
T _{amb} = -40) °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
S(OFF)	OFF-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	±1.0	μΑ
lcc	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	40	μА
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	490	μА

[1] Typical values are measured at T_{amb} = 25 °C.



10. Dynamic characteristics

Table 9. Dynamic characteristics 74HC4066

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see <u>Figure 12</u>.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		-40	°C to +85	o°C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	90 18 15 12 225 45 - 38 30 150 30 - 26	
t _{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; see <u>Figure 10</u>	[2]						
		V _{CC} = 2.0 V		-	8	75	-	90	ns
		V _{CC} = 4.5 V		-	3	15	-	18	ns
		V _{CC} = 6.0 V		-	2	13	-	15	ns
		V _{CC} = 9.0 V		-	2	10	-	90 18 15 12 225 45 - 38 30 150 30 -	ns
t _{off}	turn-off time	nE to nY or nZ; see Figure 11	[4]					- 225	
		V _{CC} = 2.0 V		-	44	190	-		ns
		V _{CC} = 4.5 V		-	16	16 38 - 45	45	ns	
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	13	-	-	-	ns
		V _{CC} = 6.0 V		-	13	33	-	38	ns
		V _{CC} = 9.0 V		-	16	26	-	90 18 15 12 225 45 - 38 30 150 30 - 26	ns
t _{on}	turn-on time	nE to nY or nZ; see Figure 11	[3]						
		V _{CC} = 2.0 V		-	36	125	-	150	ns
		V _{CC} = 4.5 V		-	13	25	-	30	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	11	-	-	-	ns
		V _{CC} = 6.0 V		-	10	21	-	26	ns
		V _{CC} = 9.0 V		-	8	16	-	20	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC}	[5]	11		-	-	-	pF

- [1] Typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [3] t_{on} is the same as t_{PHZ} and t_{PLZ} .
- [4] t_{off} is the same as t_{PZH} and t_{PZL} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}{}^2 \times f_o\}$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = sum of outputs;$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics 74HCT4066

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see <u>Figure 12</u>.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	ameter Conditions		-40	°C to +85	S °C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; see Figure 10	2]						
		V _{CC} = 4.5 V		-	3	15	-	18	ns
t _{off}	turn-off time	nE to nY or nZ; see Figure 11	4]						
		V _{CC} = 4.5 V		-	20	44	-	53	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	16	-	-	-	ns
t _{on}	turn-on time	nE to nY or nZ; see Figure 11	3]						
		V _{CC} = 4.5 V		-	12	30	-	36	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	12	-	-	-	ns
C _{PD}	power dissipation capacitance	per switch; V _I = GND to (V _{CC} – 1.5 V)	<u>5]</u>	-	12	-	-	-	pF

- [1] Typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PHL} and t_{PLH}.
- [3] t_{on} is the same as t_{PHZ} and t_{PLZ} .
- [4] t_{off} is the same as t_{PZH} and t_{PZL} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}{}^2 \times f_o\}$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

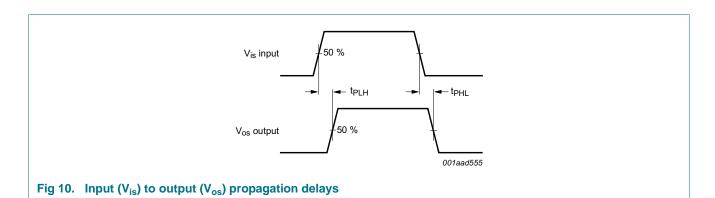
 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_0\} = \text{sum of outputs};$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

11. Waveforms



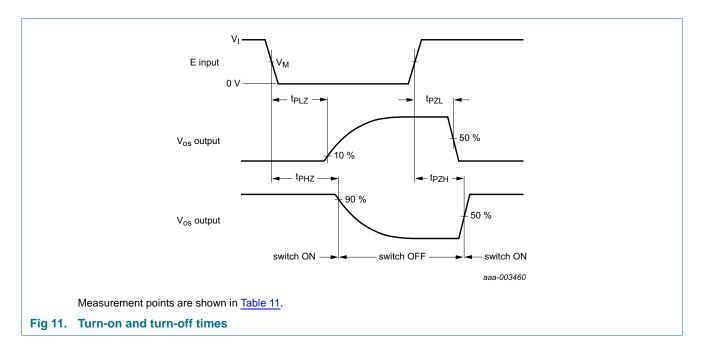
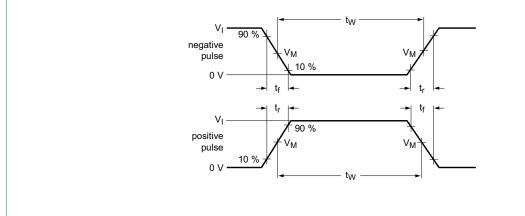
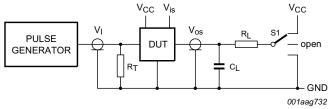


Table 11. Measurement points

Туре	V _I	V _M
74HC4066	V_{CC}	0.5V _{CC}
74HCT4066	3.0 V	1.3 V





Test data is given in Table 12.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 12. Test circuit for measuring switching times

Table 12. Test data

Test	Input		Output	Output Switch Z (Yn)		
	Control E	E Switch Yn (Z) t _r				
	V _I [1]	V _{is}		C _L	R _L	
t _{PHL} , t _{PLH}	GND	GND to V _{CC}	6 ns	50 pF	-	open
t _{PHZ} , t _{PZH}	GND to V _{CC}	V _{CC}	6 ns	50 pF, 15 pF	1 kΩ	GND
t _{PLZ} , t _{PZL}	GND to V _{CC}	GND	6 ns	50 pF, 15 pF	1 kΩ	V _{CC}

[1] For 74HCT4066: maximum input voltage $V_I = 3.0 \text{ V}$.

12. Additional dynamic characteristics

Table 13. Additional dynamic characteristics

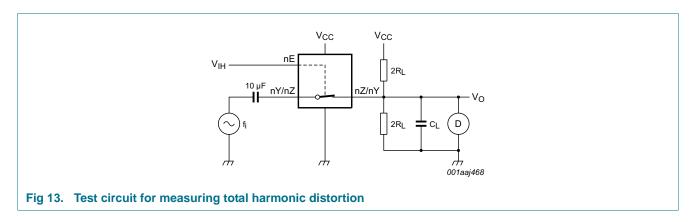
Recommended conditions and typical values; GND = 0 V; T_{amb} = 25 °C.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

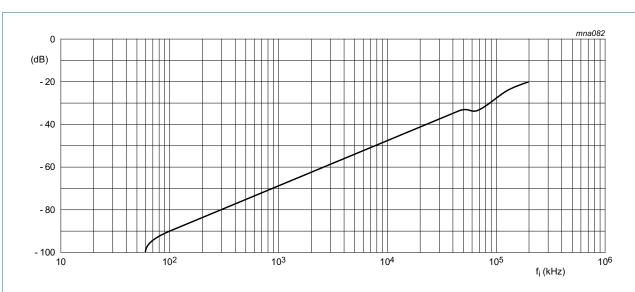
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	f_i = 1 kHz; R_L = 10 k Ω ; C_L = 50 pF; see Figure 13				%
		V _{CC} = 4.5 V; V _I = 4.0 V (p-p)	-	0.04	-	%
		$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.02	-	%
		f_i = 10 kHz; R_L = 10 k Ω ; C_L = 50 pF; see Figure 13				
		V _{CC} = 4.5 V; V _I = 4.0 V (p-p)	-	0.12	-	%
		$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.06	-	%
f _(-3dB)	-3 dB frequency response	$R_L = 50 \Omega$; $C_L = 10 pF$; see <u>Figure 15</u>				
		V _{CC} = 4.5 V	-	180	-	MHz
		V _{CC} = 9.0 V	-	200	-	MHz
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $C_L = 50 pF$; $f_i = 1 MHz$; see Figure 14				
		V _{CC} = 4.5 V	-	-50	-	dB
		V _{CC} = 9.0 V	-	-50	-	dB
V _{ct}	crosstalk voltage	between digital input and switch (peak to peak value); $R_L = 600 \Omega$; $C_L = 50 pF$; $f_i = 1 MHz$; see Figure 16				
		V _{CC} = 4.5 V	-	110	-	mV
		V _{CC} = 9.0 V	-	220	-	mV
Xtalk	crosstalk	between switches; R _L = 600 Ω ; C _L = 50 pF; [1] f_i = 1 MHz; see Figure 17				
		V _{CC} = 4.5 V	-	-60	-	dB
		V _{CC} = 9.0 V	-	-60	-	dB

- [1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
- [2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for f_i = 1 MHz (0 dBm = 1 mW into 50 Ω). After set-up, f_i is increased to obtain a reading of -3 dB at V_{os} .

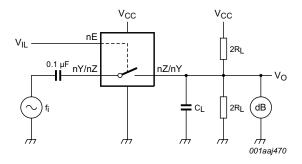


74HC_HCT4066

All information provided in this document is subject to legal disclaimers.



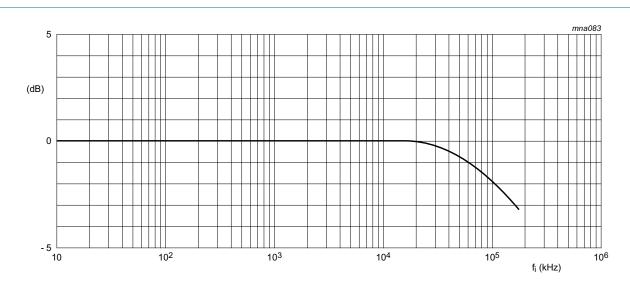
a. Isolation (OFF-state)



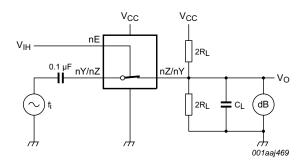
b. Test circuit

 V_{CC} = 4.5 V; GND = 0 V; R_L = 600 Ω ; R_{source} = 1 k Ω .

Fig 14. Isolation (OFF-state) as a function of frequency



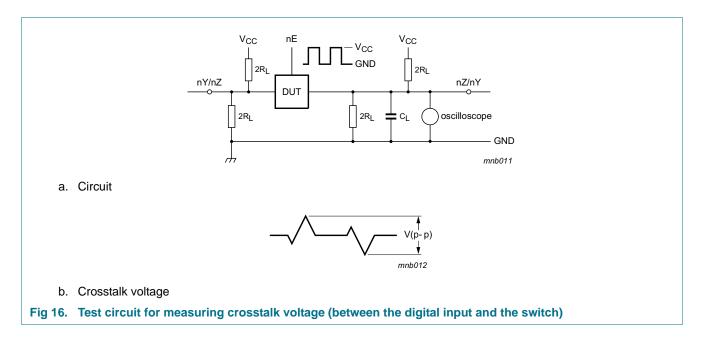
a. Typical -3 dB frequency response

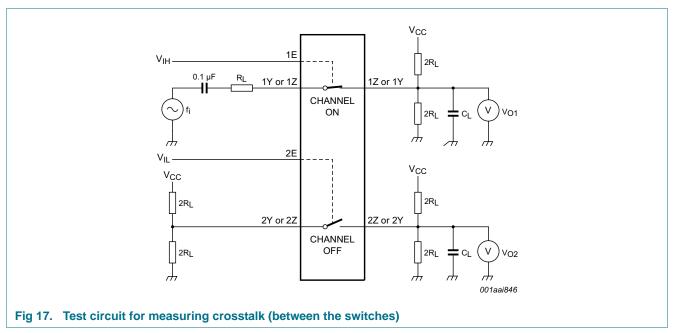


b. Test circuit

 V_{CC} = 4.5 V; GND = 0 V; R_L = 50 $\Omega;$ R_{source} = 1 $k\Omega.$

Fig 15. -3 dB frequency response

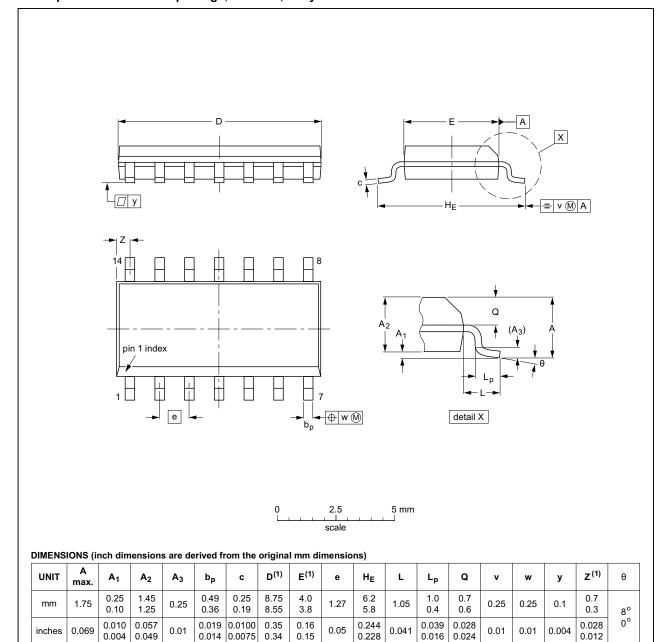




13. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

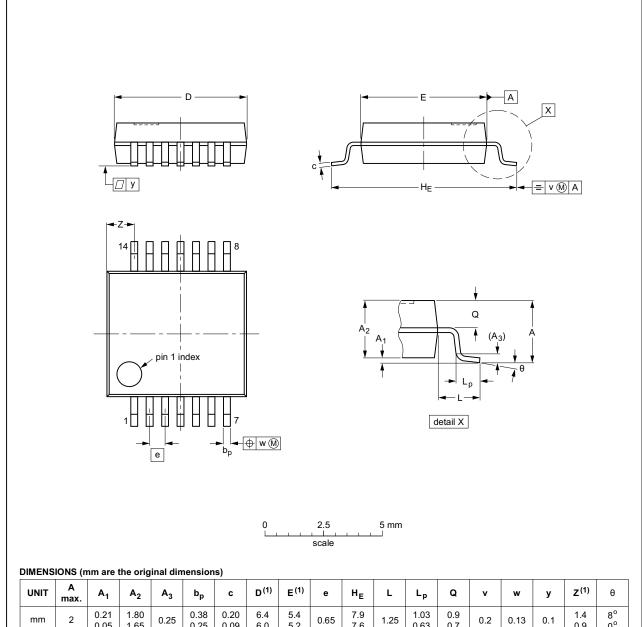
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

Fig 18. Package outline SOT108-1 (SO14)

74HC_HCT4066

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT337-1		MO-150				99-12-27 03-02-19

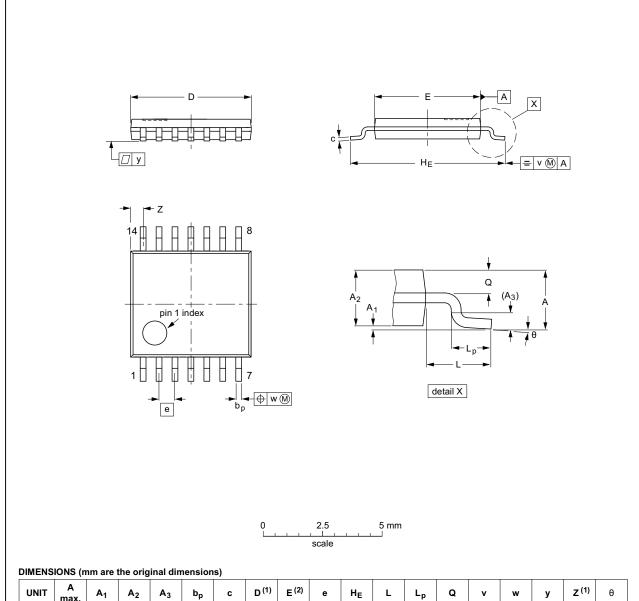
Fig 19. Package outline SOT337-1 (SSOP14)

74HC_HCT4066

All information provided in this document is subject to legal disclaimers.

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



						-,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	TLINE REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT402-1		MO-153			99-12-27 03-02-18	
					03-02-16	

Fig 20. Package outline SOT402-1 (TSSOP14)

74HC_HCT4066

All information provided in this document is subject to legal disclaimers.

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm

SOT762-1

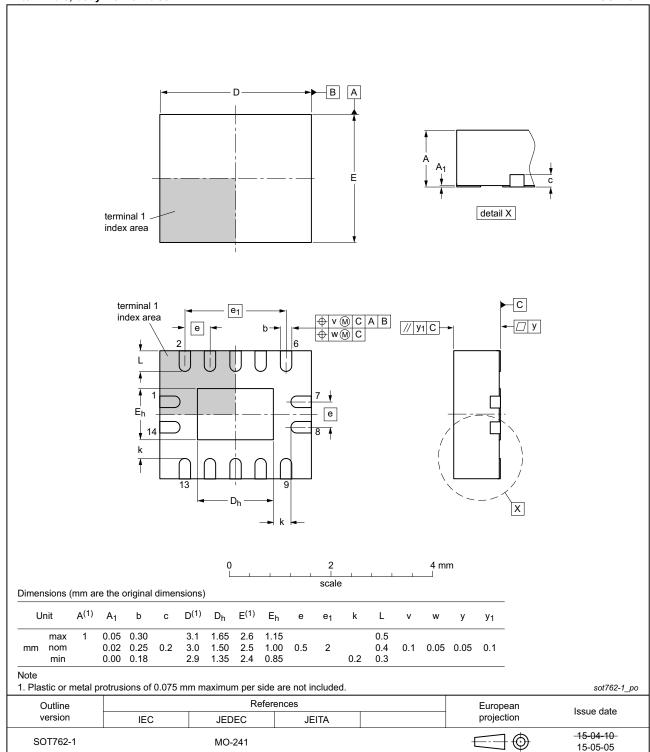


Fig 21. Package outline SOT762-1 (DHVQFN14)

74HC_HCT4066

All information provided in this document is subject to legal disclaimers.

14. Abbreviations

Table 14. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4066 v.8	20151203	Product data sheet	-	74HC_HCT4066 v.7
Modifications:	Type numbers	s 74HC4066N and 74HCT4066	SN (SOT27-1) remov	ved.
74HC_HCT4066 v.7	20130402	Product data sheet	-	74HC_HCT4066 v.6
Modifications:	Descriptive tit	le corrected (errata).		
	New general	description (errata).		
74HC_HCT4066 v.6	20120718	Product data sheet	-	74HC_HCT4066 v.5
Modifications:		this data sheet has been rede	signed to comply wi	th the new identity
	 Legal texts ha 	ave been adapted to the new c	ompany name wher	e appropriate.
74HC_HCT4066 v.5	20041111	Product data sheet	-	74HC_HCT4066 v.4
74HC_HCT4066 v.4	20030617	Product data sheet	-	74HC_HCT4066_CNV v.3
74HC_HCT4067_CNV v.3	19981110	Product data sheet	-	74HC_HCT4066_CNV v.2
74HC_HCT4066_CNV v.2	19981002	Product specification	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

74HC_HCT4066

74HC4066; 74HCT4066

Quad single-pole single-throw analog switch

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

18. Contents

1	General description
2	Features and benefits
3	Ordering information
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description
6	Functional description 3
7	Limiting values4
8	Recommended operating conditions 4
9	Static characteristics 5
10	Dynamic characteristics
11	Waveforms
12	Additional dynamic characteristics 13
13	Package outline
14	Abbreviations
15	Revision history
16	Legal information
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks23
17	Contact information 23
18	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Nexperia:

74HC4066PW 74HC4066DB 74HC4066N,652

NXP:

74HC4066BQ,115 74HC4066D,652 74HC4066DB,112 74HC4066DB,118 74HC4066D,653 74HC4066PW,112 74HC4066PW,118 74HCT4066BQ,115 74HCT4066D,112 74HCT4066DB,112 74HCT4066DB,118 74HCT4066PW,118